

2.0 V, 32/16 kB, smaRTClock, 12-Bit ADC MCU

Analog Peripherals

12-bit ADC

- ±1 LSB INL; no missing codes
- Programmable Throughput up to 200 ksps
- Up to 24 External Inputs; programmable as single-ended or differential
- Data Dependent Windowed Interrupt Generator
- Built-in Temperature Sensor (±3 °C)
- Internal Voltage Reference—1.5 V, 2.2 V (programmable)

Two 12-Bit Current Mode DACs

Two Comparators

- Programmable hysteresis values and response time
- Configurable to generate interrupts or reset

POR/Brown-out Detector

On-Chip Debug

- On-chip debug circuitry facilitates full speed, non-intrusive in-system debug (no emulator required)
- Provides breakpoints, single stepping, watchpoints
- Inspect/modify memory, registers, and stack
- Superior performance to emulation systems using ICE-chips, target pods, and sockets

Supply Voltage: 2.0-5.25 V

- Built-in LDO regulator: 2.1 V or 2.5 V

smaRTClock™

- Battery switchover circuit
- Back-up power supply
- Oscillator failure detect
- Operates down to 1 V

High-Speed 8051 CPU

- Pipelined instruction architecture; executes 70% of instructions in 1 or 2 system clocks
- Up to 50 MIPS throughput with 50 MHz system clock
- Expanded interrupt handler

Memory

- 2304 bytes data RAM
- 16 kB, 32 kB Flash; in-system programmable in 512-Byte Sectors; Full Read/Write/Erase Functionality at 2.25 V_{DD}
- 64 bytes battery-backed RAM

Digital Peripherals

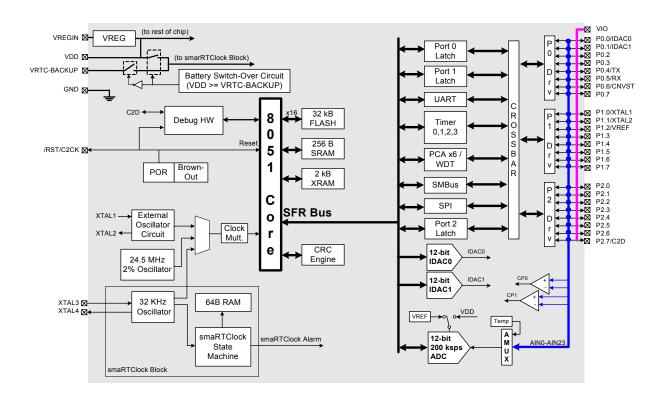
- 24 port I/O; up to 5.25 V tolerance
- Hardware SMBus[™] (I2C[™] compatible), SPI[™], and UART serial ports available concurrently
- 16-bit programmable counter array with six capture/compare modules, WDT
- 4 general-purpose 16-bit counter/timers

Clock Sources

- Internal Oscillators: 24.5 MHz, 2% Accuracy Supports UART Operation; Clock Multiplier up to 50 MHz
- External Oscillator: Crystal, RC, C, or Clock (1 or 2 pin modes)
- External smaRTClock Oscillator: 32 kHz Crystal or self resonant oscillator
- Fast wake up from suspend mode in <1 μs
- Can switch between clock sources on-the-fly

Available in 28-Pin QFN and 32-Pin LQFP

Temperature Range: -40 to +85 °C



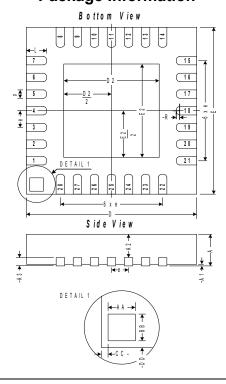


Selected Electrical Specifications

 $(T_A = -40 \text{ to } +85 \text{ C}^{\circ}, V_{DD} = 2.0 \text{ V} \text{ unless otherwise specified})$

Parameter	Conditions	Min	Тур	Max	Units
Global Characteristics					
Supply Input Voltage (V _{REGIN})	Output Current = 1 mA	2.15	_	5.25	V
Core Supply Voltage (V _{DD})		2.0	_	2.75	V
I/O Supply Voltage (V _{IO})	V _{IO} ≤ VREGIN	2.0	_	5.25	V
Supply Voltage (V _{RTC BACKUP})		1.0	_	5.25	V
Supply Current with CPU active	V _{DD} = 2.0 V Clock = 32 kHz Clock = 1 MHz	_	13 0.3	_	μA mA
	Clock = 50 MHz	_	9.5	_	mA
Supply Current (shutdown)	Chip off; smaRTClock off Chip off; smaRTClock running V _{BAT} = 1.0 V Chip off; smaRTClock running V _{DD} = 1.8 V	_ _	<0.1 0.6 0.8		μΑ μΑ μΑ
Clock Frequency Range	Chip on, ornare Clock farming VDD 1.0 V	DC	_	50	MHz
Internal Oscillator					
Frequency		24	24.5	25	MHz
D/A Converter					
Resolution			12		bits
Differential Nonlinearity	Guaranteed Monotonic	_	_	± 1	LSB
Settling Time		_	5	_	μs
A/D Converters					
Resolution			12		bits
Integral Nonlinearity		_	_	± 1	LSB
Differential Nonlinearity	Guaranteed Monotonic	_	_	± 1	LSB
Signal-to-Noise Plus Distortion		64	_	_	dB
Throughput Rate		_	_	200	ksps

Package Information



C8051F41xDK Development Kit

